

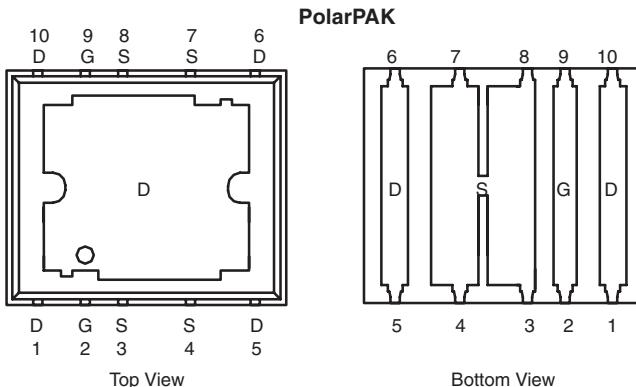
## N-Channel 40-V (D-S) MOSFET

### PRODUCT SUMMARY

V <sub>DS</sub> (V)	R <sub>DS(on)</sub> ( $\Omega$ )	I <sub>D</sub> (A) <sup>a</sup>		Q <sub>g</sub> (Typ.)
		Silicon Limit	Package Limit	
40	0.0055 at V <sub>GS</sub> = 10 V	103	50	25 nC
	0.007 at V <sub>GS</sub> = 4.5 V	91	50	

Package Drawing

[www.vishay.com/doc?73398](http://www.vishay.com/doc?73398)



Top surface is connected to pins 1, 5, 6, and 10

Ordering Information: SiE832DF-T1-E3 (Lead (Pb)-free)

SiE832DF-T1-GE3 (Lead (Pb)-free and Halogen-free)

### FEATURES

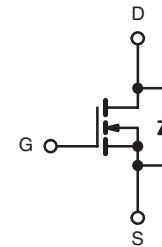
- Halogen-free According to IEC 61249-2-21 Definition
- TrenchFET® Power MOSFET
- Ultra Low Thermal Resistance Using Top-Exposed PolarPAK® Package for Double-Sided Cooling
- Leadframe-Based New Encapsulated Package
  - Die Not Exposed
  - Same Layout Regardless of Die Size
- Low Q<sub>gd</sub>/Q<sub>gs</sub> Ratio Helps Prevent Shoot-Through
- 100 % R<sub>g</sub> and UIS Tested
- Compliant to RoHS directive 2002/95/EC



RoHS  
COMPLIANT  
HALOGEN  
**FREE**  
Available

### APPLICATIONS

- VRM
- Point-of-Load
- Synchronous Rectification



N-Channel MOSFET

For Related Documents  
[www.vishay.com/ppg?74414](http://www.vishay.com/ppg?74414)

### ABSOLUTE MAXIMUM RATINGS T<sub>A</sub> = 25 °C, unless otherwise noted

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V <sub>DS</sub>	40	V
Gate-Source Voltage	V <sub>GS</sub>	± 20	
Continuous Drain Current (T <sub>J</sub> = 150 °C)	I <sub>D</sub>	103 (Silicon Limit)	A
		50 <sup>a</sup> (Package Limit)	
		50 <sup>a</sup>	
		23.6 <sup>b, c</sup>	
		18.9 <sup>b, c</sup>	
Pulsed Drain Current	I <sub>DM</sub>	80	mJ
Continuous Source-Drain Diode Current	I <sub>S</sub>	50 <sup>a</sup>	
		4.3 <sup>b, c</sup>	
Single Pulse Avalanche Current	I <sub>AS</sub>	35	
Avalanche Energy	E <sub>AS</sub>	61	
Maximum Power Dissipation	P <sub>D</sub>	104	W
		66	
		5.2 <sup>b, c</sup>	
		3.3 <sup>b, c</sup>	
Operating Junction and Storage Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	- 55 to 150	°C
Soldering Recommendations (Peak Temperature) <sup>d, e</sup>		260	

Notes:

- Package limited is 50 A.
- Surface Mounted on 1" x 1" FR4 board.
- t = 10 s.
- See Solder Profile ([www.vishay.com/doc?73257](http://www.vishay.com/doc?73257)). The PolarPAK is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection.
- Rework Conditions: manual soldering with a soldering iron is not recommended for leadless components.

**THERMAL RESISTANCE RATINGS**

Parameter		Symbol	Typical	Maximum	Unit
Maximum Junction-to-Ambient <sup>a, b</sup>	Steady State	$R_{thJA}$	20	24	°C/W
Maximum Junction-to-Case (Drain Top) <sup>a</sup>		$R_{thJC}$ (Drain)	1	1.2	
Maximum Junction-to-Case (Source) <sup>a, c</sup>		$R_{thJC}$ (Source)	2.8	3.4	

Notes:

- a. Surface Mounted on 1" x 1" FR4 board.
- b. Maximum under Steady State conditions is 68 °C/W.
- c. Measured at source pin (on the side of the package).

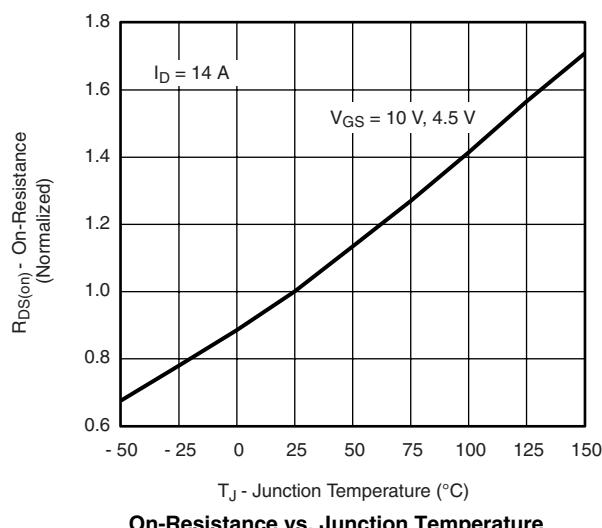
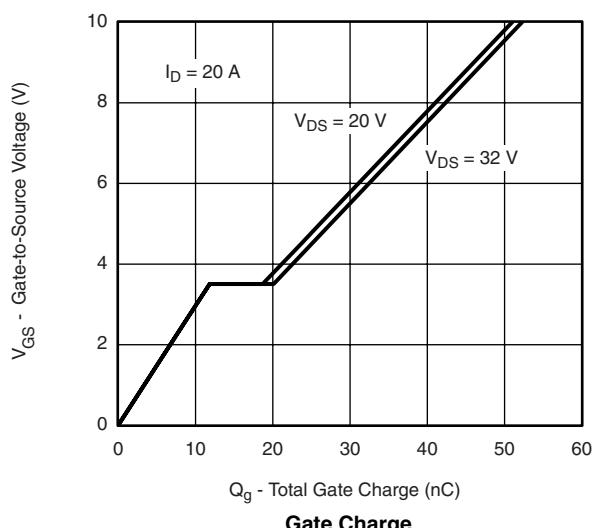
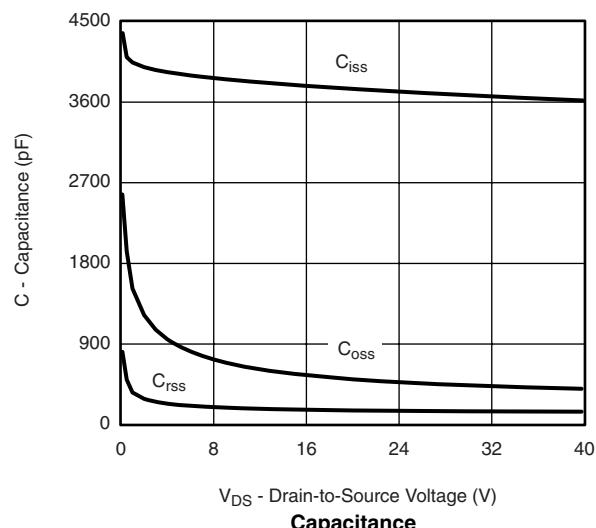
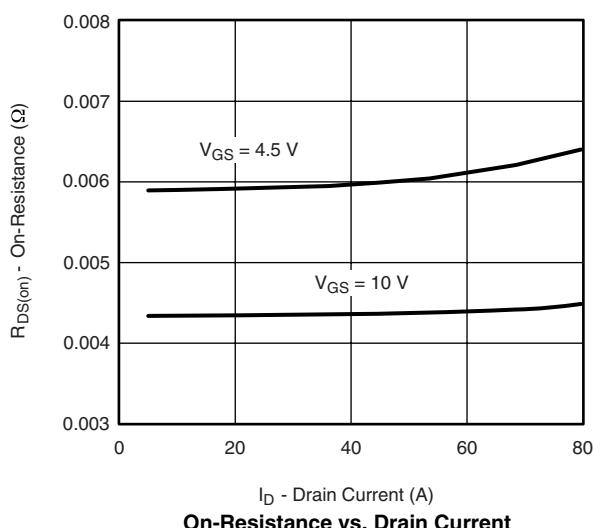
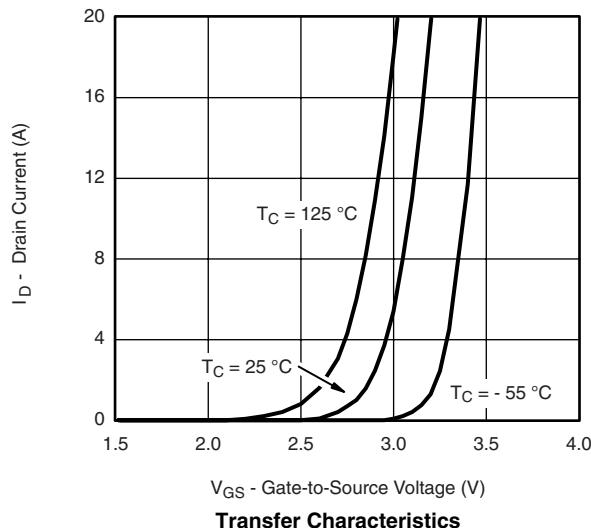
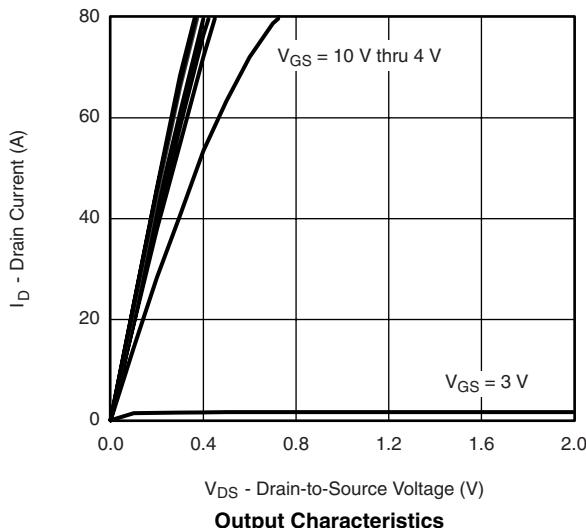
**SPECIFICATIONS**  $T_J = 25^\circ\text{C}$ , unless otherwise noted

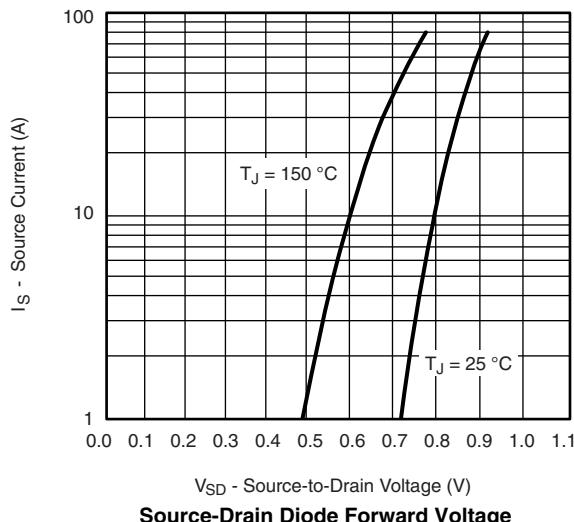
Parameter	Symbol	Test Conditions	Min.	Typ.	Max.	Unit
<b>Static</b>						
Drain-Source Breakdown Voltage	$V_{DS}$	$V_{GS} = 0 \text{ V}, I_D = 250 \mu\text{A}$	40			V
$V_{DS}$ Temperature Coefficient	$\Delta V_{DS}/T_J$	$I_D = 250 \mu\text{A}$		43.1		mV/°C
$V_{GS(th)}$ Temperature Coefficient	$\Delta V_{GS(th)}/T_J$			- 6.9		
Gate-Source Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D = 250 \mu\text{A}$	1.5	2.2	3.0	V
Gate-Source Leakage	$I_{GSS}$	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$			$\pm 100$	nA
Zero Gate Voltage Drain Current	$I_{DSS}$	$V_{DS} = 40 \text{ V}, V_{GS} = 0 \text{ V}$			1	μA
		$V_{DS} = 40 \text{ V}, V_{GS} = 0 \text{ V}, T_J = 55^\circ\text{C}$			10	
On-State Drain Current <sup>a</sup>	$I_{D(on)}$	$V_{DS} \geq 5 \text{ V}, V_{GS} = 10 \text{ V}$	25			A
Drain-Source On-State Resistance <sup>a</sup>	$R_{DS(on)}$	$V_{GS} = 10 \text{ V}, I_D = 14 \text{ A}$		0.0046	0.0055	Ω
		$V_{GS} = 4.5 \text{ V}, I_D = 12 \text{ A}$		0.0058	0.007	
Forward Transconductance <sup>a</sup>	$g_{fs}$	$V_{DS} = 15 \text{ V}, I_D = 13.6 \text{ A}$		86		S
<b>Dynamic<sup>b</sup></b>						
Input Capacitance	$C_{iss}$	$V_{DS} = 20 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ MHz}$		3800		pF
Output Capacitance	$C_{oss}$			510		
Reverse Transfer Capacitance	$C_{rss}$			160		
Total Gate Charge	$Q_g$	$V_{DS} = 20 \text{ V}, V_{GS} = 10 \text{ V}, I_D = 20 \text{ A}$		51	77	nC
Gate-Source Charge	$Q_{gs}$			25	38	
Gate-Drain Charge	$Q_{gd}$			12		
Gate Resistance	$R_g$	$f = 1 \text{ MHz}$		7		Ω
Turn-On Delay Time	$t_{d(on)}$			1.1	1.7	
Rise Time	$t_r$	$V_{DD} = 20 \text{ V}, R_L = 2 \Omega$ $I_D \cong 10 \text{ A}, V_{GEN} = 4.5 \text{ V}, R_g = 1 \Omega$		45	70	ns
Turn-Off Delay Time	$t_{d(off)}$			260	400	
Fall Time	$t_f$			35	55	
Turn-On Delay Time	$t_{d(on)}$			55	85	
Rise Time	$t_r$			15	25	
Turn-Off Delay Time	$t_{d(off)}$	$V_{DD} = 20 \text{ V}, R_L = 2 \Omega$ $I_D \cong 10 \text{ A}, V_{GEN} = 10 \text{ V}, R_g = 1 \Omega$		30	45	ns
Fall Time	$t_f$			35	55	
				10	15	
<b>Drain-Source Body Diode Characteristics</b>						
Continuous Source-Drain Diode Current	$I_S$	$T_C = 25^\circ\text{C}$			50	A
Pulse Diode Forward Current <sup>a</sup>	$I_{SM}$				80	
Body Diode Voltage	$V_{SD}$	$I_S = 10 \text{ A}$		0.8	1.2	V
Body Diode Reverse Recovery Time	$t_{rr}$	$I_F = 10 \text{ A}, dI/dt = 100 \text{ A}/\mu\text{s}, T_J = 25^\circ\text{C}$		85	130	ns
Body Diode Reverse Recovery Charge	$Q_{rr}$			110	170	
Reverse Recovery Fall Time	$t_a$			64		
Reverse Recovery Rise Time	$t_b$			21		

Notes:

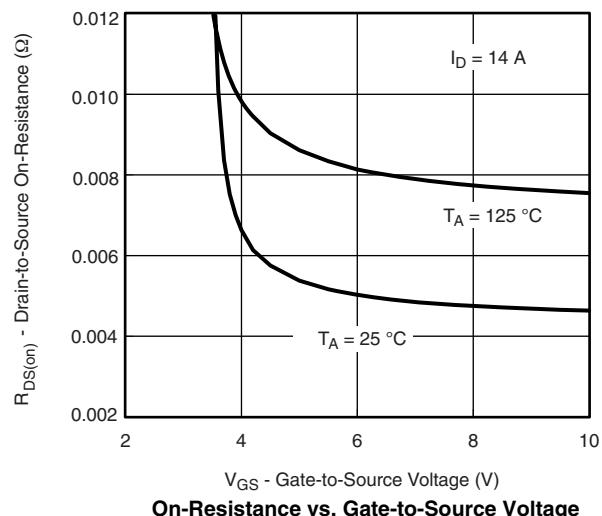
- a. Pulse test; pulse width  $\leq 300 \mu\text{s}$ , duty cycle  $\leq 2 \%$
- b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

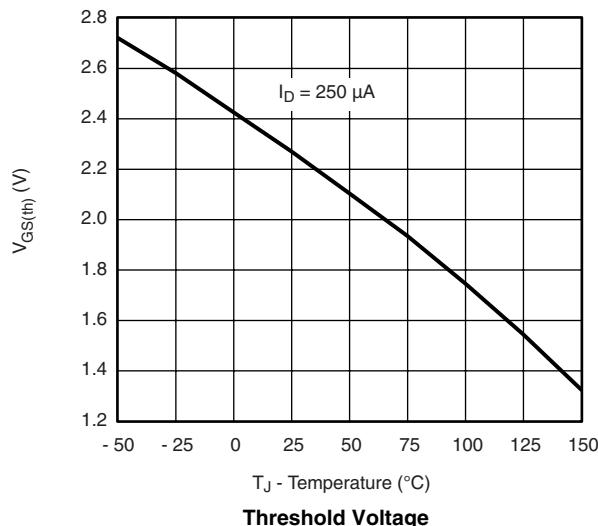
**TYPICAL CHARACTERISTICS** 25 °C, unless otherwise noted


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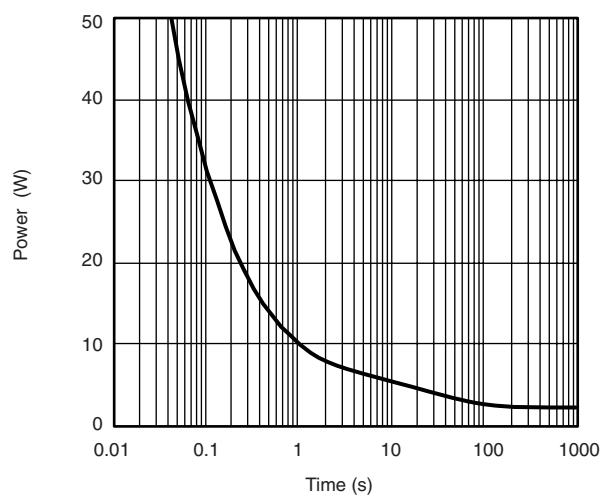
$V_{SD}$  - Source-to-Drain Voltage (V)  
Source-Drain Diode Forward Voltage



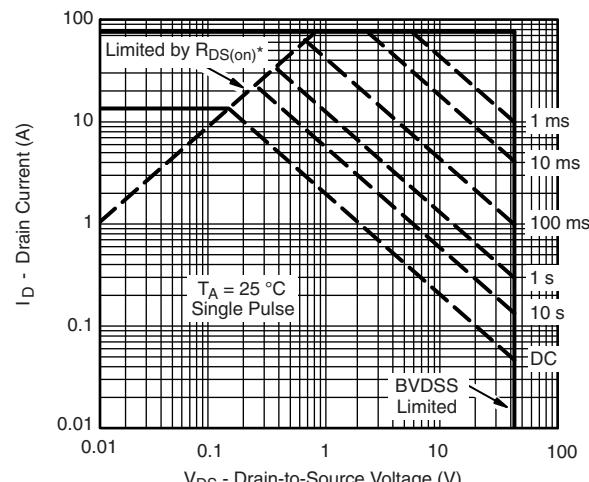
$R_{DS(on)}$  - Drain-to-Source On-Resistance (Ω)  
On-Resistance vs. Gate-to-Source Voltage



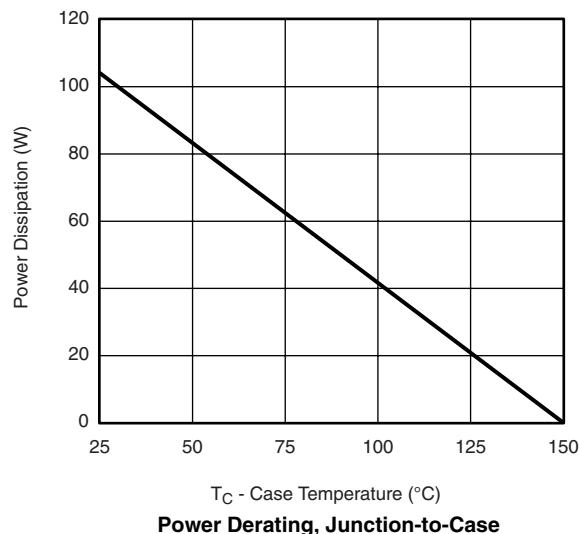
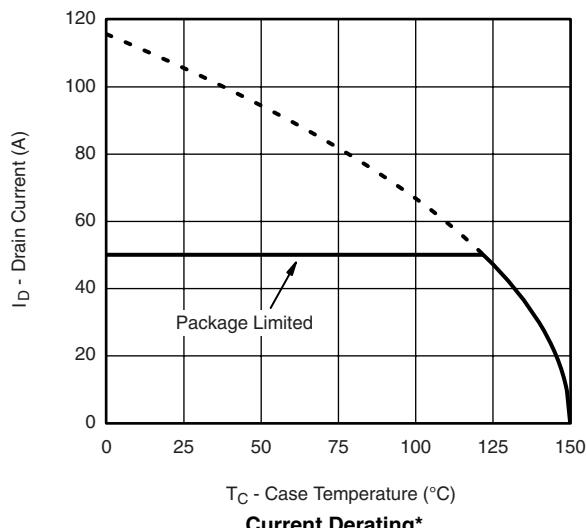
$V_{GS(th)}$  - Threshold Voltage  
 $T_J$  - Temperature (°C)



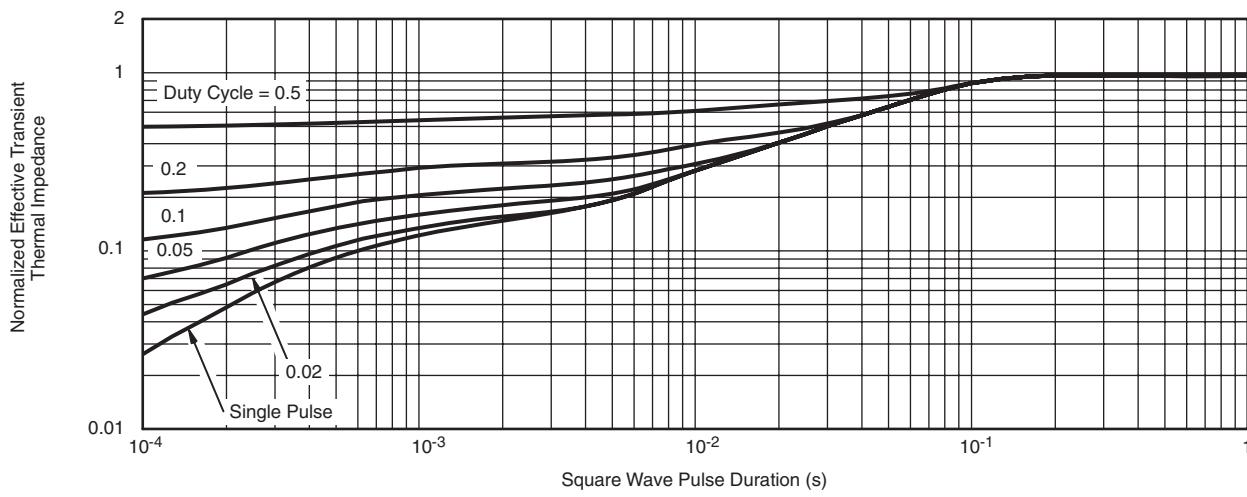
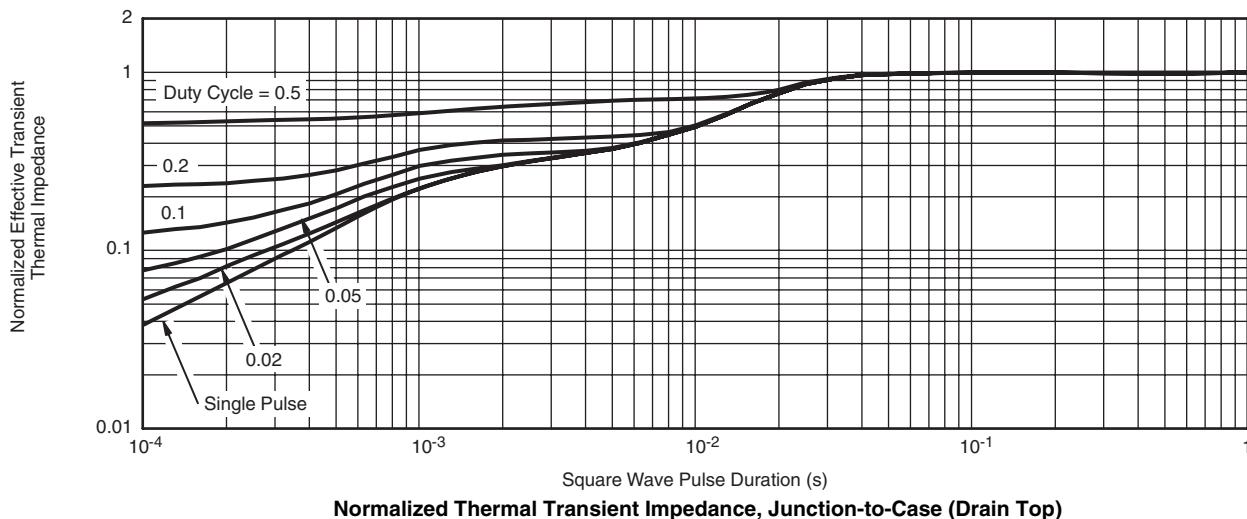
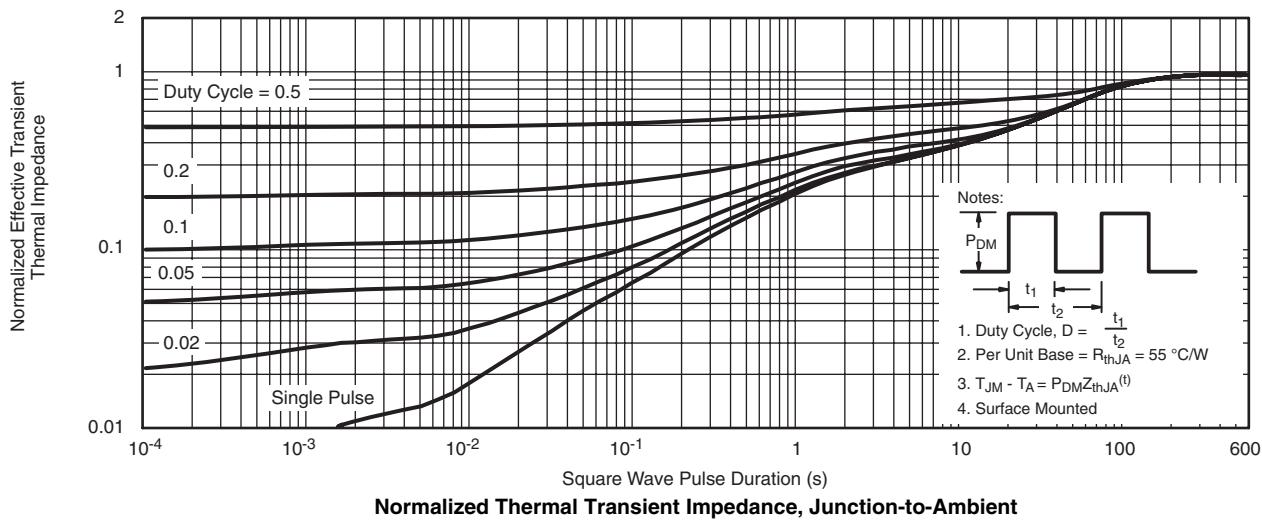
Single Pulse Power, Junction-to-Ambient



Limited by  $R_{DS(on)}$   
 $* V_{GS} > \text{minimum } V_{GS} \text{ at which } R_{DS(on)} \text{ is specified}$   
Safe Operating Area, Junction-to-Ambient

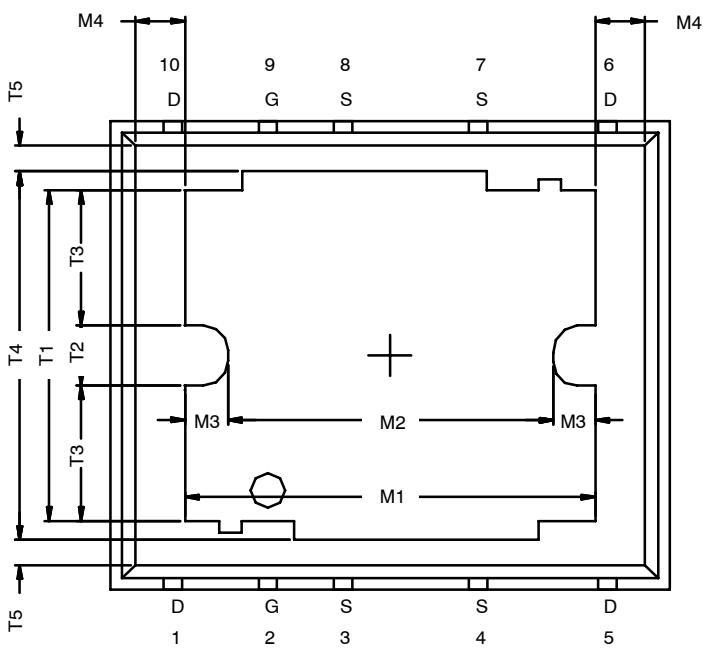
**TYPICAL CHARACTERISTICS** 25 °C, unless otherwise noted


\* The power dissipation  $P_D$  is based on  $T_{J(max)} = 150$  °C, using junction-to-case thermal resistance, and is more useful in settling the upper dissipation limit for cases where additional heatsinking is used. It is used to determine the current rating, when this rating falls below the package limit.

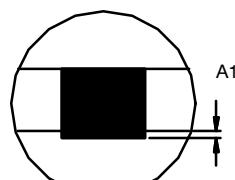
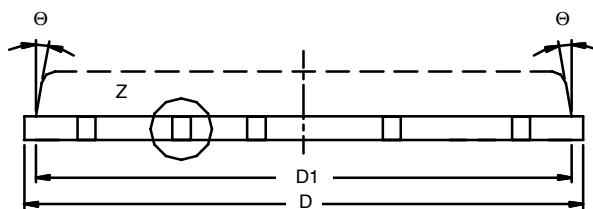
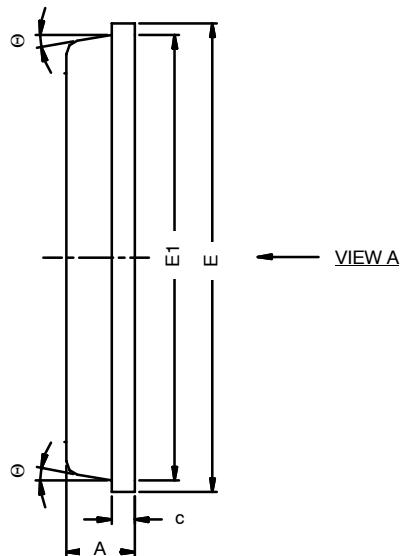
**TYPICAL CHARACTERISTICS** 25 °C, unless otherwise noted

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see [www.vishay.com/ppg?74414](http://www.vishay.com/ppg?74414).

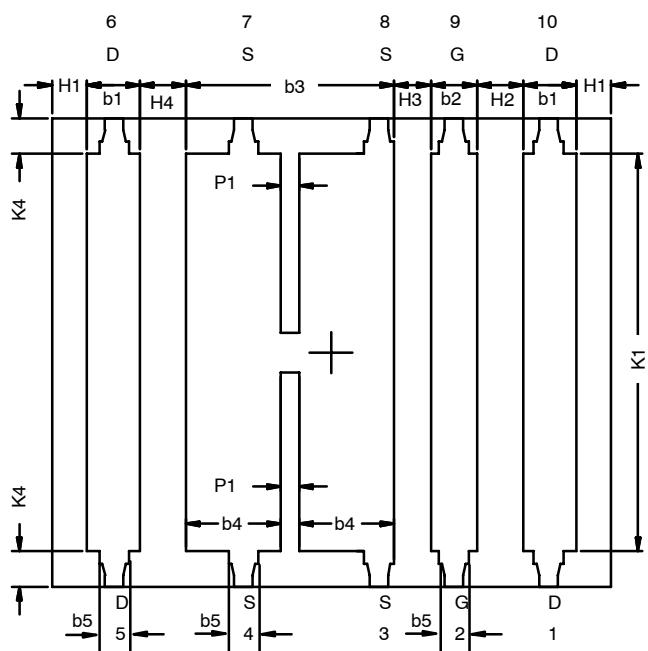
## **PolarPAK™ (Option S)**



Product datasheet/information page contain links to applicable package drawing.



## DETAIL Z



VIEW A

# Package Information

Vishay Siliconix

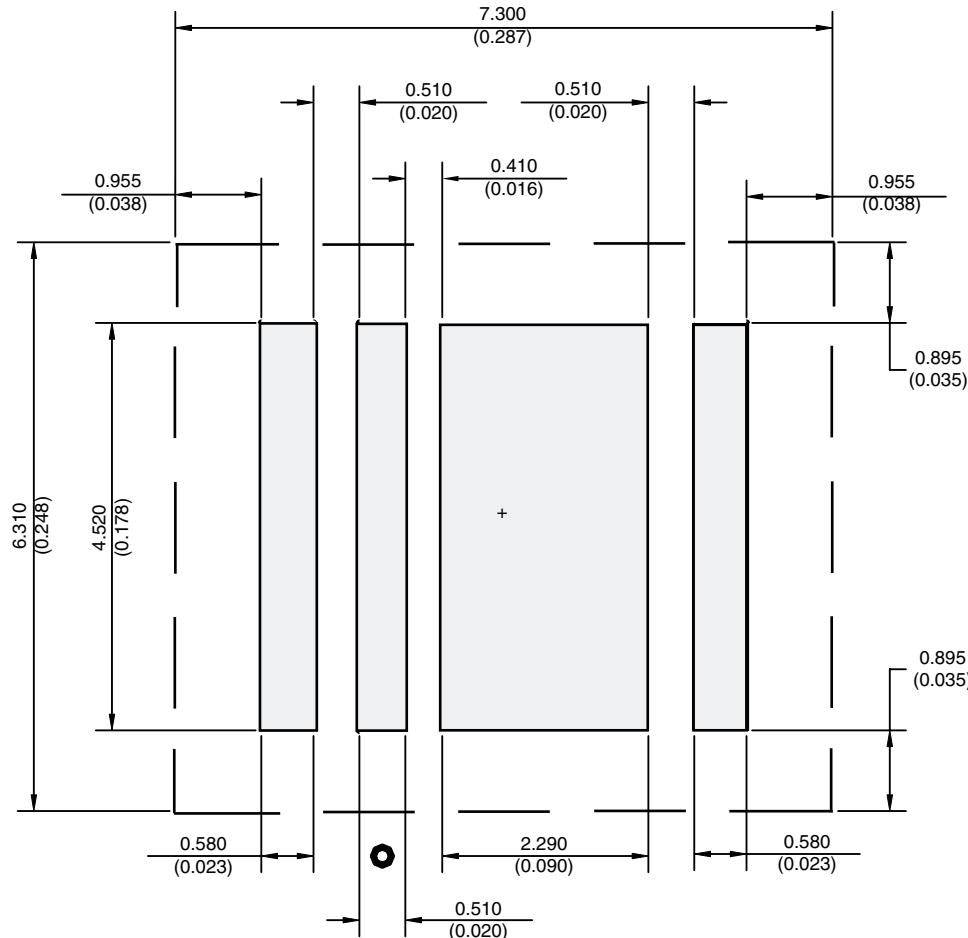


Dim	MILLIMETERS			INCHES		
	Min	Nom	Max	Min	Nom	Max
<b>A</b>	0.75	0.80	0.85	0.030	0.031	0.033
<b>A1</b>	0.00	—	0.05	0.000	—	0.002
<b>b1</b>	0.48	0.58	0.68	0.019	0.023	0.027
<b>b2</b>	0.41	0.51	0.61	0.016	0.020	0.024
<b>b3</b>	2.19	2.29	2.39	0.086	0.090	0.094
<b>b4</b>	0.89	1.04	1.19	0.035	0.041	0.047
<b>b5</b>	0.23	0.33	0.43	0.009	0.013	0.017
<b>c</b>	0.20	0.25	0.30	0.008	0.010	0.012
<b>D</b>	6.00	6.15	6.30	0.236	0.242	0.248
<b>D1</b>	5.74	5.89	6.04	0.226	0.232	0.238
<b>E</b>	5.01	5.16	5.31	0.197	0.203	0.209
<b>E1</b>	4.75	4.90	5.05	0.187	0.193	0.199
<b>H1</b>	0.23	—	—	0.009	—	—
<b>H2</b>	0.45	—	0.56	0.020	—	0.022
<b>H3</b>	0.31	0.41	0.51	0.012	0.016	0.020
<b>H4</b>	0.45	—	0.56	0.020	—	0.022
<b>K1</b>	4.22	4.37	4.52	0.166	0.172	0.178
<b>K4</b>	0.24	—	—	0.009	—	—
<b>M1</b>	4.30	4.50	4.70	0.169	0.177	0.185
<b>M2</b>	3.43	3.58	3.73	0.135	0.141	0.147
<b>M3</b>	0.22	—	—	0.009	—	—
<b>M4</b>	0.05	—	—	0.002	—	—
<b>P1</b>	0.15	0.20	0.25	0.006	0.008	0.010
<b>T1</b>	3.48	3.64	4.10	0.137	0.143	0.150
<b>T2</b>	0.56	0.76	0.95	0.022	0.030	0.037
<b>T3</b>	1.20	—	—	0.051	—	—
<b>T4</b>	3.90	—	—	0.154	—	—
<b>T5</b>	0	0.18	0.36	0.000	0.007	0.014
<b>Θ</b>	0°	10°	12°	0°	10°	12°

ECN: S-51049 Rev. B, 13-Jun-05  
DWG: 5947

Note: Millimeters govern over inches

## RECOMMENDED MINIMUM PADS FOR PolarPAK® Option L and S



Recommended Minimum for PolarPAK Option L and S

Dimensions in mm/(Inches)

No External Traces within Broken Lines

Dot indicates Gate Pin (Part Marking)



## Disclaimer

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